RESOLUTION OF CONTROVERSY OF MECHANISM OF VOLTAGE-GATING IN ION CHANNELS

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A controversy dominating ion channel research regarded the mechanism of voltage-gating in ion channels. In this communication, we analyzed the two leading models of voltage-gating in terms of the thermodynamic ease of membrane insertion of the voltage-sensing protein module from a comprehensive set of potassium channels and a representative sodium channel. The voltage sensor of the KvAP channel was an outlier in the plot of free energy of membrane insertion of voltage sensors. The KvAP voltage sensor had a very unusual amino acid composition that supported large gating movements in its native lipid membrane. This was not typical of the majority of voltage sensors. Therefore, we resolve the controversy by arguing that neither of the two models of voltage-gating is wholly correct. Each model of voltage-gating is applicable to only a mutually-exclusive set of ion channels. The large motion of the voltage-sensor during gating proposed by the paddle model of gating is unlikely to be so large for the majority of ion channels whose voltage sensors are not located at the membrane-cytoplasm interface in the channel closed state.

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I INTRODUCTION

With the determination of the structure of a voltage-gated K^+ channel¹, a controversy emerged in the neuroscience community regarding a contradiction in the principle of voltage-gating in ion channels. Two competing models of voltage-gating were fielded backed by convincing evidence for both, and the growing body of experimental evidence has merely increased the controversy². In this work we attempt to seek a resolution to the controversy without neglecting any evidence. The voltagesensing S4 helix in all voltage-gated ion channels consists of arginine residues at intervals of third position, and the movement of these gating charges 'activates' the channel. The canonical model posits that the S4, in the channel closed state, is surrounded by protein which provide an aqueous crevice to shield it from the lipid bilayer. Upon depolarisation, the S4 undergoes small vertical displacements of \sim 2-3 A to initiate conformational changes associated with channel opening $3, 4$. The competing model of voltage-gating, called the 'paddle model,' stipulates that the S4, in the channel closed state, is located at the membrane-cytoplasm interface, and upon depolarization, undergoes a large transverse movement of \sim 20 A to translocate to the extracellular side and gate the channel $5, 6, 7$.

2 METHODS

The paddle model is supported primarily by studies with the KvAP channel in its native lipid membrane. Experimental studies with other voltage-gated K^+ channels, especially the eukaryotic Shaker channel, have unambiguously supported the alternative 'canonical' model. Shrivastava et al considered whether the KvAP channel is 'different' from other voltage-gated K^+ channels⁸ and concluded otherwise based on the conservation of the essential S4 motif of basic residues.

Hessa et al developed an amino acid hydrophobicity scale 9 . In a subsequent study, this hydrophobicity scale was applied to the determination of the free energy (ΔG) of membrane insertion of the KvAP voltage sensor¹⁰. This was found to be almost 0 kcal/mol, providing the essential thermodynamic support for the location of the KvAP voltage sensor at the membrane-cytoplasm interface in the channel closed state. Here our objective is to extend the investigation of thermodynamic stability of the voltage sensor to more contentious sequences of voltage sensors. We constructed a comprehensive dataset of 147 90% non-redundant voltage-gated K^+ channels representing various subfamilies including KCNA (Shaker), KCNB (Shab), KCNC (Shaw), KCND (Shal), KCNF, KCNG, and KCNS. The ΔG of membrane insertion of the voltage sensor of each channel was computed using the amino acid hydrophobicity scale.

3 RESULTS AND DISCUSSION

Fig. 1 shows the ΔG of membrane insertion for the voltage sensors in the comprehensive dataset. It was seen that all the S4 sequences possessed a significant positive free energy, which would in turn function to impede all large motions in the lipid environment of the membrane. Therefore it is unlikely that these voltage sensors were located at the membrane-cytoplasm interface in the channel closed state, since such a location would entail large movements of the voltage sensor in the membrane during gating. This result provided support for the 'canonical' model of gating for the majority of voltage sensors. On the other hand, the KvAP S4 sequence was clearly the outlier in the data, with its ΔG of membrane insertion more than 3-sigma away from the mean ΔG . Therefore, the extension of conclusions drawn with respect to the KvAP channel is a subtle issue. The paddle model of gating is limited to those channels with an 'interfacial' S4 in the closed state. This does not seem to the case for the majority of voltage sensors based on thermodynamic evidence. It is worth noting that the ΔG of membrane insertion of the voltage sensors of channels homologous to the eukaryotic KCND subfamily were

Figure 1 ΔG values of membrane insertion of voltage sensors of a comprehensive (prokaryotic and eukaryotic) set of 147 90% non-redundant K + -channels, grouped by homology to the closest eukaryotic subfamily (given). KvAP has the lowest ΔG of membrane insertion. After correction for position-dependence, the KvAP value is close to zero¹⁰.

as high as 16 kcal/mol. The voltage-gating properties of the prokaryotic one-domain sodium channel NaChBac might be more similar to KvAP than the Shaker channel¹¹. Figure 1 also shows the ΔG of membrane insertion of the voltage sensor of this channel, which is midway between KvAP and the rest of the dataset.

Fig. 2 shows the distribution of residue frequencies in the same comprehensive set of channels compared with the KvAP S4. It was seen that seven of the 18 residues in the

Figure 2 Distribution of residue frequencies of the comprehensive set vs KvAP. The comprehensive set does not match KvAP's peakedness for hydrophobic composition. Below, alignment of the consensus S4 sequence of the comprehensive set with the KvAP and NaChBac S4 sequences. Arginines are highlighted.

KvAP S4 were leucines, whereas the comprehensive set had about three leucines on average. A variety of less hydrophobic residues such as M, A, T, H, and K were seen in the universal group but absent in the KvAP sequence. Also shown in fig. 2 is the alignment of the consensus sequence of the comprehensive set with the KvAP and NaChBac S4 sequences. The consensus sequence differed from the KvAP sequence in a total of 12 out of the 18 positions. On the contrary, the consensus sequence differed from the Shaker S4 sequence in only one position (position #10: I \leftrightarrow V). (See fig. 3 for comprehensive alignment.)

4 CONCLUSION

The ΔG of membrane insertion of the voltage sensor constrains the magnitude of its translocation in the lipid membrane during gating. The higher the ΔG , the greater is the constraint for movement. The KvAP voltage sensor has the lowest ΔG , and is therefore capable of maximum translocation. As ΔG increases, there is a continuum of possible translocations of decreasing magnitude. The majority of voltage sensors clearly prefer minimal translocation during gating. In addition to the distinctiveness of the KvAP voltage sensor we have shown, recent results from Dr. R. MacKinnon's lab^{12} indicated that the composition of the phospholipid membrane of *Aeropyrum pernix* might play a role. The KvAP channel is able to effect gating by the paddle mechanism through a better thermodynamic accommodation of the voltage sensor in the channel open and closed states. We conclude that there is co-evolution between the compositions of the voltage sensor and the phospholipid membrane. This co-evolution is reminiscent of the coevolution between catalysis and regulation in potassium channels¹³. Future directions include ascertaining correlation in the compositions of protein and membrane and its correspondence with the choice of gating mechanism.

Figure 3 Alignment of 90% non-redundant S4 sequences from the comprehensive dataset. Accession codes refer to the Genbank Gene Products database. At the top is KvAP, and the percent values denote homology to the KvAP sequence in terms of sequence identity. The degree of homology between the KvAP S4 and all the other S4 sequences is <40% in every case, with only 17% homologies also observed.

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